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November 2014

## **FSA551 Dual SPST Depletion Mode Audio Switch**

### **Features**

- Dual SPST
- Depletion Mode Technology
- . -3 dB Bandwidth: 240 MHz
- V<sub>CC-OFF</sub>: 1.5 V to 3.0 V
- V<sub>CC-ON</sub>: 0 V to 0.2 V
- V<sub>SW-OFF</sub>: -0.3 V to 3 V
- V<sub>SW-ON</sub>: -0.3 V to 3 V -
- R<sub>ON</sub>: 0.38 Ω Typical
- R<sub>ON</sub> Flat: 0.01 Ω (Typical)
- THD+N: 0.0005% (Typical)
- Fairchild Green, RoHS Compliant, Halogen Free

### Description

The FSA551 is a high-performance dual single-pole single-throw (SPST x 2) audio switch. The Depletion Mode technology allows the device to conduct signals when there is no  $V_{CC}$  available and to isolate signals when V<sub>CC</sub> is present. During signal conduction, the Depletion Mode gate control allows the FSA551 to achieve excellent THD+N performance while consuming minimal power.

### **Related Resources**

FSA551 Evaluation Board

### **Applications**

- Smart Phones
- Tablets, Ultra Books

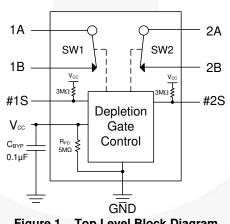
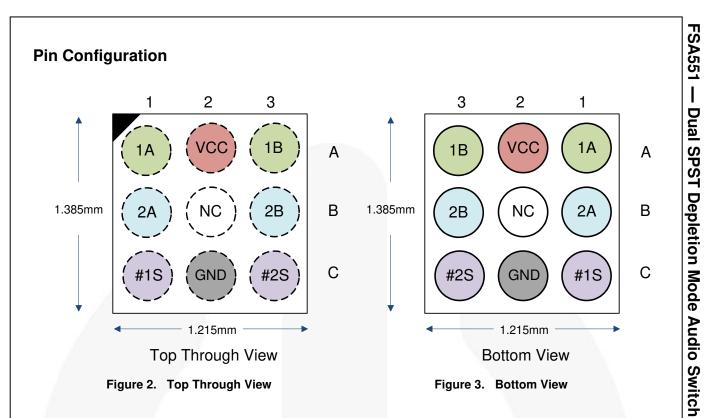


Figure 1. Top Level Block Diagram

### **Ordering Information**

Part Number	Operating Temperature Range	Top Mark	Package	Packing Method
FSA551UCX	-40 to 85°C	U9	9-Ball WLCSP, 0.40 mm Pitch, 1.215 x 1.385 x 0.58 mm (Nominal)	3000 Units on Tape & Reel



### **Pin Descriptions**

Pin #	Name	Туре	Description
A1	1A	Depletion I/O	A-Port of Switch 1 (Normally Closed)
A3	1B	Depletion I/O	B-Port of Switch 1 (Normally Closed)
C1	#1S	Control	Select to Enable/Disable SW1 (Enable LOW)
A2	V <sub>CC</sub>	Power Supply	Power Supply Input
B2	NC	No Connect	Do Not Connect
C2	GND	Ground	Ground
B1	2A	Depletion I/O	A-Port of Switch 2 (Normally Closed)
B3	2B	Depletion I/O	B-Port of Switch 2 (Normally Closed)
C3	#2S	Control	Select to Enable/Disable SW2 (Enable LOW)

### Table 1. Depletion Mode Control Truth Table

V <sub>cc</sub>	#1S	#2S	Switch 1	Switch 2
LOW	Х	Х	ON	ON
HIGH	HIGH	HIGH	OFF	OFF
HIGH	LOW	HIGH	ON	OFF
HIGH	HIGH	LOW	OFF	ON

### Table 2. Recommended External Component

Component	Description	Vendor	Parameter	Min.	Тур.	Unit
CBYP	0.1 μF, 10%, 6.3 V, X5R, 0201	Murata GRM033R60J104K	С	0.65	0.1	μF

### **Absolute Maximum Ratings**

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Parameter		Min.	Max.	Unit
Supply/Control Voltage		-0.5	4.6	V
Control Input Voltage	#1S, #2S	-0.5	4.6	V
DC Switch I/O Voltage (Switch Conducting)	1A, 1B, 2A, 2B	-0.5	3.3	V
DC Switch I/O Voltage (Switch Isolated)	1A, 1B, 2A, 2B	-0.5	3.3	V
Switch I/O Current	V <sub>CC</sub> =0 V (Switch Conducting)		350	mA
Peak Switch Current	Pulsed at 1 ms Duration, <10% Duty Cycle		500	mA
Human Body Model, ANSI/ESDA/JEDEC	I/O Ports		7	
JS-001-2012	All Other Pins		5	
Charged Device Model, JEDEC: JESD22-C101			2	kV
	Contact		8	
1EC 61000-4-2 System	Air Gap		15	
Absolute Maximum Operating Temperature		-40	+85	°C
Thermal Resistance, Junction-to-Ambient	2S2P JEDEC std. PCB		97	°C/W
Storage Temperature		-65	+150	°C
	Supply/Control Voltage Control Input Voltage DC Switch I/O Voltage (Switch Conducting) DC Switch I/O Voltage (Switch Isolated) Switch I/O Current Peak Switch Current Human Body Model, ANSI/ESDA/JEDEC JS-001-2012 Charged Device Model, JEDEC: JESD22-C101 IEC 61000-4-2 System Absolute Maximum Operating Temperature Thermal Resistance, Junction-to-Ambient	Supply/Control VoltageControl Input Voltage#1S, #2SDC Switch I/O Voltage (Switch Conducting)1A, 1B, 2A, 2BDC Switch I/O Voltage (Switch Isolated)1A, 1B, 2A, 2BSwitch I/O CurrentV <sub>CC</sub> =0 V (Switch Conducting)Peak Switch CurrentPulsed at 1 ms Duration, <10% Duty Cycle	Supply/Control Voltage-0.5Supply/Control Voltage#1S, #2S-0.5Control Input Voltage (Switch Conducting)1A, 1B, 2A, 2B-0.5DC Switch I/O Voltage (Switch Isolated)1A, 1B, 2A, 2B-0.5DC Switch I/O CurrentV <sub>CC</sub> =0 V (Switch Conducting)-0.5Switch I/O CurrentV <sub>CC</sub> =0 V (Switch Conducting)-0.5Peak Switch CurrentPulsed at 1 ms Duration, <10% Duty Cycle	Suppl/Control Voltage-0.54.6Control Input Voltage#1S, #2S-0.54.6DC Switch I/O Voltage (Switch Conducting)1A, 1B, 2A, 2B-0.53.3DC Switch I/O Voltage (Switch Isolated)1A, 1B, 2A, 2B-0.53.3Switch I/O CurrentV <sub>CC</sub> =0 V (Switch Conducting)350350Peak Switch CurrentPulsed at 1 ms Duration, <10% Duty Cycle

### **Recommended Operating Conditions**

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding these ratings or designing to Absolute Maximum Ratings.

Symbol	Parameter		Min.	Max.	Unit
V <sub>CC(ON)</sub>	Supply Voltage with Depletion Switch Conducting (	1A=1B; 2A=2B)	0	0.2	V
V <sub>CC(OFF)</sub>	Supply Voltage with Depletion Switch Isolated (1A≠	<sup>≟</sup> 1B; 2A≠2B; #1S=#2S=HIGH)	1.5	3.0	V
V <sub>SW(ON)</sub>	DC Switch I/O Voltage	Switch Conducting	-0.3	3.0	V
V <sub>SW(OFF)</sub>	DC Switch I/O Voltage	Switch Isolated	-0.3	3.0	V
V <sub>CNTRL</sub>	Control Input Voltage	#1S, #2S	0	3.0	٧

# FSA551 — Dual SPST Depletion Mode Audio Switch

### **DC Electrical Characteristics**

Unless otherwise specified, typical values are for  $T_A=25^{\circ}C$ .

Symbol	Parameter	Condition	V <sub>cc</sub> (V)	$V_{cc}(V)$ $T_A = -40^{\circ}C \text{ to } +8$		+85°C	Unit
• ,				Min.	Тур.	Max.	•
$V_{\text{CC}(\text{HYS})}$	Supply Voltage Hysteresis				450		mV
I <sub>ON</sub>	Switch-to-GND Leakage Current (Switch Conducting)	1A=2.6 V, 1B=Float, 2A=2.6 V, 2B=Float	0		0.1	5	μA
I <sub>OFF</sub>	Switch-to-GND Leakage Current (Switch Isolated)	1A =2.6 V, 1B=GND, 2A=2.6 V, 2B=GND, #1S=#2S=V <sub>CC</sub>	1.8		0.1	10	μA
I <sub>CCT</sub>	Increase in I <sub>CC</sub> per Control Voltage	#1S or #2S=1.2 V	3.0		7	15	μA
R <sub>ON</sub>	Switch On Resistance	$I_{SW}$ =100 mA, $V_{SW}$ =-0.3 V to 3 V	0		0.38	0.60	Ω
$\Delta R_{ON}$	Switch On Resistance Difference, Channel to Channel	$I_{SW}$ =100 mA, $V_{SW}$ =-0.3 V to 3 V	0		0.01		Ω
R <sub>FLAT(ON)</sub>	On Resistance Flatness	$I_{SW}$ =100 mA, $V_{SW}$ =-0.3 V to 3 V	0		0.01		Ω
R <sub>PD</sub>	V <sub>CC</sub> Pull-Down Resistance		<0.2		5.0		MΩ
R <sub>PU</sub>	Control Pull-Up Resistance		<0.2		3.0		MΩ
	Quiescent Supply Current	Switch Isolated, #1S=#2S=V <sub>CC</sub>	1.5 - 3.0		70	120	
Icc	Quiescent Supply Current	Switch On	0.2		0.1	0.5	μA
VIH	Select Pin Input High Voltage		1.5 – 3.0	1.2			V
VIL	Select Pin Input Low Voltage		1.5 – 3.0			0.55	V

### AC Electrical Characteristics

Unless otherwise specified, typical values are for  $T_A=25^{\circ}C$ .

Symbol	Deremeter	Condition		T <sub>A</sub> =- 40°C to +85°C			Uni
Symbol	Parameter	Condition	V <sub>cc</sub> (V)	Min.	Тур.	Max.	t
t <sub>ON</sub>	Turn-On Time V <sub>CC</sub> to Output	$\begin{array}{l} R_L = 2 \ k\Omega, \ C_L = 10 \ pF, \ V_{SW} = 3 \ V, \\ (Measured \ 90/10\%), \ Figure \ 5 \end{array}$	1.8 → 0		445		μs
toff	Turn-Off Time V <sub>CC</sub> to Output	$\begin{array}{l} R_L = 2 \ k\Omega, \ C_L = 10 \ pF, \ V_{SW} = 3 \ V, \\ (Measured \ 90/10\%), \ Figure \ 5 \end{array}$	0 → 1.8		175		μs
tons	Turn-On Time Control Pin	$_{n}$ A=2 kΩ to 2.85 V, $_{n}$ B=1 Ω//10 pF to GND, # $_{n}$ S= 1.8 $\rightarrow$ 0 V, (Measured 20/80%), Figure 5	1.8		205		μs
toffs	Turn-Off Time Control Pin	nA=2 kΩ to 2.85 V, nB=1 Ω//10 pF to GND, #nS= 0 → 1.8 V, (Measured 20/80%), Figure 4, Figure 5	1.8		29		μs
Oirra	Port A Off Isolation	$_{n}A=2 k\Omega$ to GND, $_{n}B=1 \Omega$ to GND, # $_{n}S=V_{CC}$ , Port B V <sub>SW</sub> =600 mV <sub>PP</sub> Ground Referenced, (Measure at f=20 kHz), Figure 7	1.8		-75		dB
O <sub>IRRB</sub>	Port B Off Isolation	$_{n}A=2 k\Omega$ to 2.85 V, $_{n}B=1 \Omega$ to GND, $\#_{n}S=V_{CC}$ , Port A V <sub>DC</sub> + 300 mV <sub>PP(AC)</sub> , (Measure at f=20 kHz), Figure 6	1.8		-100		dB
BW	-3dB Bandwidth	$R_L=2 k\Omega, C_L=0 pF$	0		240		MHz
THD+N	Total Harmonic Distortion + Noise	$\begin{array}{l} R_{\text{L}}{=}2 \ \text{k}\Omega, \ \text{f}{=}20 \ \text{Hz} \ \text{to} \ 20 \ \text{kHz}, \\ \text{DC Bias}{=}0 \ \text{V}, \ \text{V}_{\text{SW}}{=}600 \ \text{mV}_{\text{PP}}, \\ \text{Measurement BW} < 22 \ \text{kHz} \end{array}$	0		0.0005		%

### Capacitance

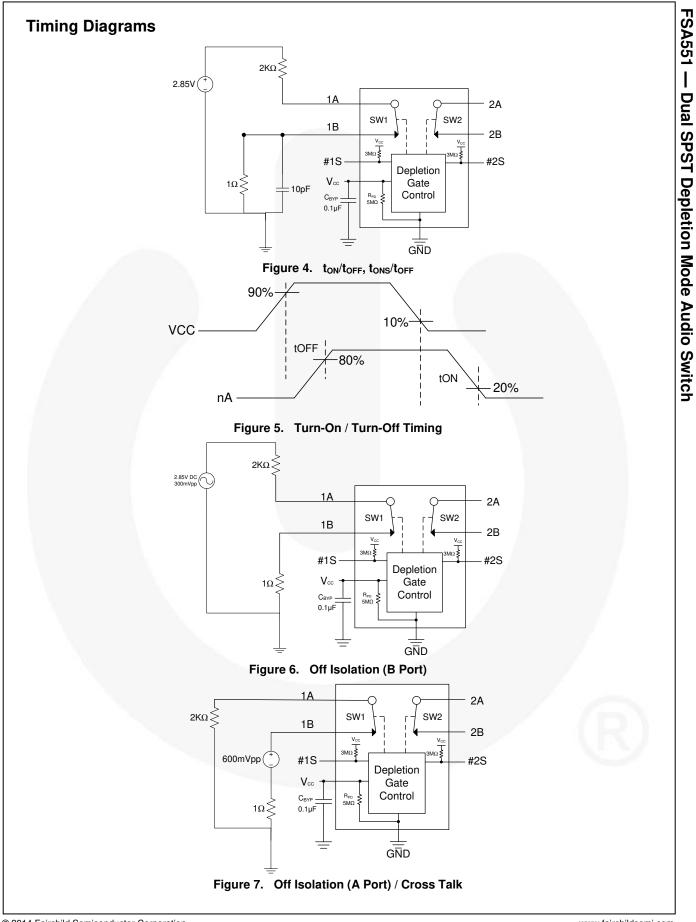
Symbol	Parameter	Condition		T <sub>A</sub> = +25°C			Unit
Symbol	Parameter	Condition	V <sub>cc</sub> (V)	Min.	Тур.	Max.	Unit
Con	On Capacitance	f=1 MHz, 400 mV <sub>PP</sub> , 1A, 1B, 2A, 2B	0		21		pF
C <sub>OFF</sub>	Off Capacitance	f=1 MHz, 400 mV <sub>PP</sub> , 1A, 1B, 2A, 2B, #1S=#2S=V <sub>CC</sub>	1.8		25	/	pF
C <sub>CTRL</sub>	Control Pin Capacitance	f=1 MHz, 400 mV <sub>PP</sub> , #1S, #2S	1.8		2.5		pF

### **Oscillator Frequency**

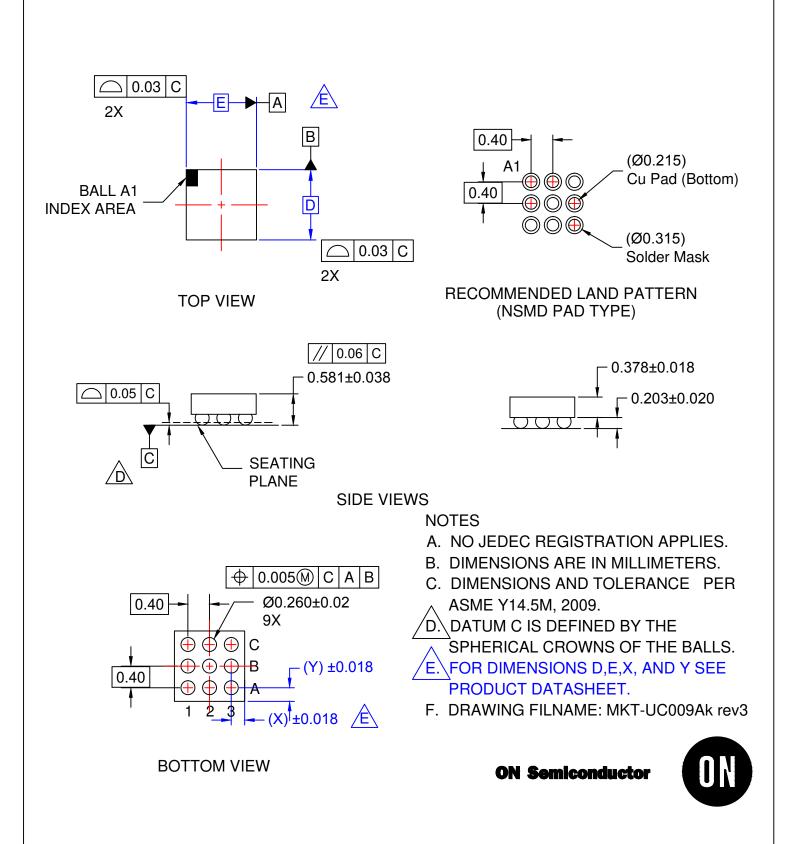
Symbol	Peremeter	Condition		/	T <sub>A</sub> = +25	°C	Unit
Symbol	Parameter	Condition	$V_{cc}(V)$	Min.	Тур.	Max.	Unit
f <sub>osc</sub>	Oscillator Frequency <sup>(1)</sup>	Oscillator Enabled	1.8		775		kHz
f <sub>OSC%</sub>	Oscillator Frequency Tolerance Over Process & Temperature <sup>(1)</sup>	Oscillator Enabled	1.8			30	%

Note:

1. Parameters guaranteed by Design and Characterization.



E	D	X	Y
l.215±.03 mm	1.385±.03 mm	0.2075 mm	0.2925 mm



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